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Sheet 1 of 1

FORM PTO-1449 (REV. 7-80)	U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE	Atty. Docket No. 13171 (YO999-509)	Serial No. Unassigned
LIST OF PRIOR ART CITED BY APPLICANT (Use several sheets if necessary)		Applicants Cyril Cabral, Jr., et al.	
		Filing Date Herewith	Group Unassigned

JC821 U.S. PRO 09/96/954 11/27/01

U.S. PATENT DOCUMENTS

EXAMINER INITIAL*		DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE (if appropriate)
EK	AA	5,510,295	4/23/96	Cabral, Jr. et al.	—	—	—
EK	AB	5,608,226	3/4/97	Yamada et al.	—	—	—
EK	AC	5,624,869	4/29/97	Agnello et al.	—	—	—
EK	AD	5,828,131	10/27/98	Cabral, Jr. et al.	—	—	—
	AE						
	AF						
	AG						
	AJ						

FOREIGN PATENT DOCUMENTS

		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION	
							YES	NO
	AK							
	AL							

OTHER PRIOR ART (Including Author, Title, Date, Pertinent Pages, Etc.)

EK	AN	M. Lawrence, et al., "Growth of Epitaxial CoSi ₂ on (100)Si," Appl. Phys. Lett., Vol. 58, No. 12, pp. 1308-1310 (1991).
EK	AO	C. Cabral, et al., "In-Situ X-Ray Diffractin and Resistivity Analysis of CoSi ₂ Phase Formation With and Without a Ti Interlayer at Rapid Thermal Annealing Rates," Mat. Res. Soc. Symp. Proc., Vol. 375, pp. 253-258 (1995).
	AP	

EXAMINER *Erik K.* DATE CONSIDERED *7/10/02*

* EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.